Sheet 1 of 1

Date Mailed: June 26, 2007

FORM 1449* SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT	Docket Number: STFD.071US	Application Number: 10/590,223	
IN AN APPLICATION	Applicant: LIU et al.		
(Use several sheets if necessary)	Filing Date: Aug. 21, 2006	Group Art Unit: 2812	

				U.S. PATENT DOCUMEN	rs		
EXAMINER INIT IA L	DOCU	MENT NO.	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF A PPROPRI AT E
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	WO2005	/094254	13/10/2005	WIPO			
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EXAMINER	/Savitri Mulpuri/ (08/26/2008)	DATE CONSIDERED

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form for next communication to the Applicant.